

NX7660JC

InGaAsP STRAINED DC-PBH LASER DIODE MODULE 1 625 nm TELEMETRY APPLICATION

DESCRIPTION

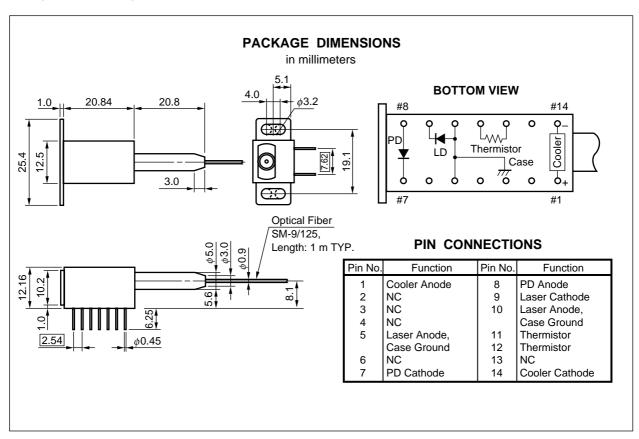
The NX7660JC is a 1 625 nm newly developed Strained Multiple Quantum Well (St-MQW) structure laser diode DIP module with single mode fiber and internal thermoelectric cooler. It is designed for light sources of telemetry equipment.

FEATURES

★ • Output power P_f = 5 mW MIN. @ I_F = 65 mA CW

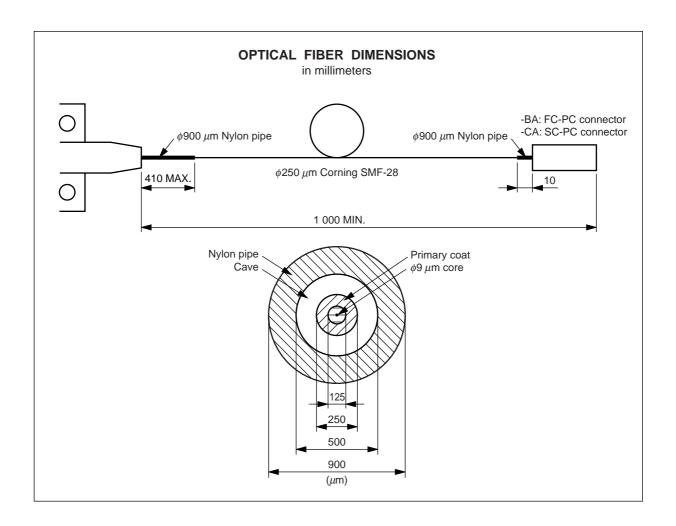
• Long Wavelength $\lambda c = 1 625 \text{ nm}$

- Wide operating temperature range $Tc = -5 \text{ to } +70 \,^{\circ}\text{C}$
 - Internal thermoelectric cooler, thermistor
 - · Hermetically sealed 14-pin DIP package
 - · Single mode fiber pigtail



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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



ORDERING INFORMATION

Part Number	Available Connector
NX7660JC	Without Connector
NX7660JC-BA	With FC-PC Connector
NX7660JC-CA	With SC-PC Connector

★ ABSOLUTE MAXIMUM RATINGS (Tc = 25 °C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Forward Current of LD	lF	200	mA
Reverse Voltage of LD	VR	2.0	V
Forward Current of PD	lF	10	mA
Reverse Voltage of PD	VR	20	V
Cooler Current	Ic	1.2	Α
Cooler Voltage	Vc	2.5	V
Operating Case Temperature	Tc	−5 to +70	°C
Storage Temperature	T _{stg}	-40 to +85	°C
Lead Soldering Temperature (10 s)	Tsld	260	°C

★ ELECTRO-OPTICAL CHARACTERISTICS (T_{LD} = 25 °C, T_C = -5 to +70 °C)

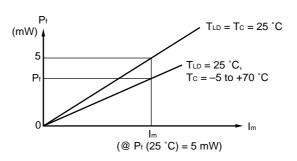
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Forward Voltage	VF	P _f = 5 mW		1.1	1.5	V
Threshold Current	Ith			15	30	mA
Optical Output Power from Fiber	Pf	IF = 65 mA	5			mW
Operating Current	lop	P _f = 5 mW		65	75	mA
Differential Efficiency form Fiber	η d		0.08	0.15		W/A
Center Wavelength	λc	P _f = 5 mW, RMS	1 615	1 625	1 635	nm
Spectral Width	σ	P _f = 5 mW, RMS		2.5	5	nm

★ ELECTRO-OPTICAL CHARACTERISTICS

(Applicable to Monitor PD: $TLD = 25 \,^{\circ}C$, Tc = -5 to $+70 \,^{\circ}C$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Monitor Current	lm	V _R = 5 V, P _f = 5 mW	50	150	260	μΑ
Monitor Dark Current	lσ	V _R = 5 V		1.0	10	nA
Tracking Error	γ*1	Im = const.			0.5	dB

*1
$$\gamma = \left| 10 \log \frac{P_f}{5 \text{ mW}} \right|$$



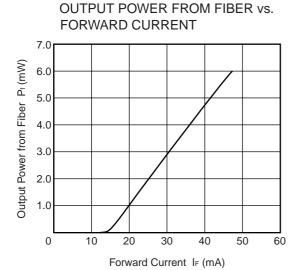
★ ELECTRO-OPTICAL CHARACTERISTICS

(Applicable to Thermistor and TEC: T_{LD} = 25 °C, T_{C} = -5 to +70 °C)

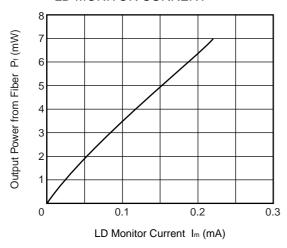
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Thermistor Resistance	R		9.5	10.0	10.5	kΩ
B Constant	В		3 300	3 400	3 500	K
Cooler Current	Ic	ΔT = 45 K		0.6	1.0	Α
Cooler Voltage	Vc	ΔT = 45 K		1.4	2.0	V
Cooling Capacity	∆T ^{*1}	Ic = 1.0 A	45			K

*1
$$\Delta T = |T_C - T_{LD}|$$

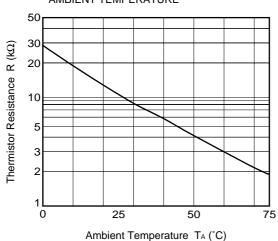
★ TYPICAL CHARACTERISTICS (TLD = 25 °C, Tc = -5 to +70 °C)



OUTPUT POWER FROM FIBER vs. LD MONITOR CURRENT

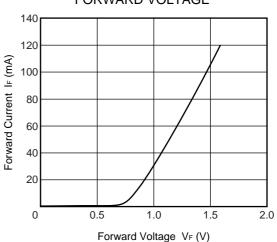


TYPICAL THERMISTOR RESISTANCE vs. AMBIENT TEMPERATURE

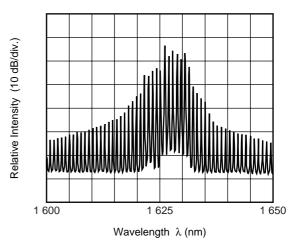


Remark The graphs indicate nominal characteristics.

FORWARD CURRENT vs. FORWARD VOLTAGE



LONGITUDINAL MODE FROM FIBER



LD FAMILY FOR DENSE WDM APPLICATION

	Absolute Max	imum Ratings	Typic	al Characte	ristics		
Part Number	Tc (°C)	T _{stg} (°C)	I _{th} (mA)	P _f (mW)	λc (nm)	Description	Package
			TYP.	MIN.	TYP.		
NX7460LE	-20 to +65	-40 to +85	25	120	1 480	1 480 nm pump LD module	BFY
NX8501 Series	0 to +65	-40 to +85	20	2	1 510	Telemetry	Coaxial
NX8561JC*1	0 to +65	-40 to +85	20	3	1 510	Telemetry	DIP
NX7660JC	−5 to +70	-40 to +85	15	5	1 625	Telemetry	DIP
NDL7910P	-20 to +70	-40 to +85	7	0.5	1 550 ^{*2}	2.5 G EA modulator integrated module	BFY
NX8562LB	-20 to +65	-40 to +85	20	20	1 550 ^{*2}	1 550 CW LD module	BFY
NX8563LB	-20 to +65	-40 to +85	20	10	ITU-T ^{*3}	1 550 CW LD module	BFY

^{*1} Under development

^{*2} Wavelength selectable for ITU-T standards upon request

^{*3} Wavelength selectable for ITU-T standards

REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system	C11159E
Quality grades on NEC semiconductor devices	C11531E
Semiconductor device mounting technology manual	C10535E
SEMICONDUCTOR SELECTION GUIDE Products & Packages (CD-ROM)	X13769X

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CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.



SEMICON	DUCTOR LASER
[]	
AVOID EX	(POSURE-Invisible
Laser Rac	diation is emitted from
this apert	ure

NEC Corporation NEC Building, 7-1, Shiba 5-chome, Minato-ku, Tokyo 108-01, Japan
Type number:
Manufactured:
Serial Number:
This product conforms to FDA
regulations as applicable
to standards 21 CFR Chapter 1.
Subchapter J.

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